CBT3251 1-of-8 FET multiplexer/demultiplexer Rev. 2 — 16 September 2013

Product data sheet

1. General description

The CBT3251 is a 1-of-8 high-speed TTL-compatible FET multiplexer/demultiplexer. The low ON-resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise.

When output enable (\overline{OE}) is LOW, the CBT3251 is enabled. S0, S1 and S2 select one of the Bn outputs for the A input data.

The CBT3251 is characterized for operation from -40 °C to +85 °C.

2. Features and benefits

- 5 Ω switch connection between two ports
- TTL-compatible input levels
- Minimal propagation delay through the switch
- Latch-up protection exceeds 100 mA per JEDEC standard JESD78 class II level A
- ESD protection:
 - HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101C exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C

3. Ordering information

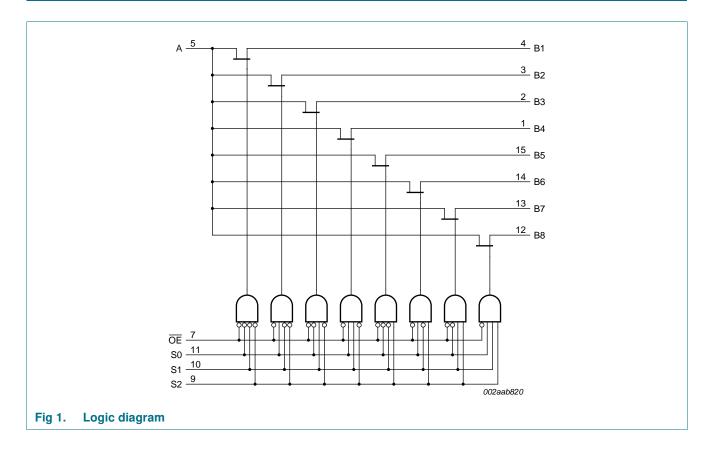
Table 1. Orde	Temperature range	Package					
		Name	Description	Version			
CBT3251D	–40 °C to +85 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1			
CBT3251DB	–40 °C to +85 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1			
CBT3251DS	–40 °C to +85 °C	SSOP16 ^[1]	plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm	SOT519-1			
CBT3251PW	–40 °C to +85 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1			

[1] Also known as QSOP16.



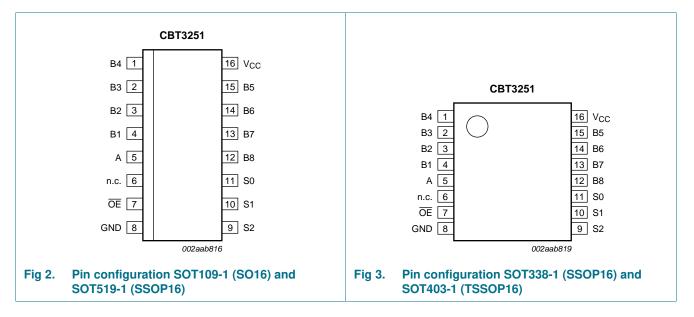
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4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2.Pin description

Symbol	Pin	Description
B1, B2, B3, B4, B5, B6, B7, B8	1, 2, 3, 4, 12, 13, 14, 15	B outputs/inputs
A	5	A input/output
n.c.	6	not connected
OE	7	output enable (active LOW)
S2, S1, S0	9, 10, 11	select control input
GND	8	ground (0 V)
V _{CC}	16	positive supply voltage

6. Functional description

Table 3. Function selection

H = HIGH voltage level; L = LOW voltage level; X = Don't care.

Inputs	nputs		Switch	Switch
OE	S2	S1	S0	
L	L	L	L	A to B1
L	L	L	Н	A to B2
L	L	Н	L	A to B3
L	L	Н	Н	A to B4
L	Н	L	L	A to B5
L	Н	L	Н	A to B6
L	Н	Н	L	A to B7
L	Н	Н	Н	A to B8
Н	Х	Х	Х	switch off

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		<u>[1]</u> –0.5	+7.0	V
I _{SW}	switch current	continuous current through each switch	-	128	mA
I _{IK}	input clamping current	V ₁ < 0 V	-50	_	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +85 \ ^{\circ}C$			
		SO16 package	[2] -	500	mW
		SSOP16 package	<u>[3]</u> _	500	mW
		TSSOP16 package	<u>[3]</u> _	500	mW

[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

[2] For SO16 package: Ptot derates linearly with 8 mW/K above 70 °C.

[3] For SSOP16 and TSSOP16 package: P_{tot} derates linearly with 5.5 mW/K above 70 °C.

8. Recommended operating conditions

Table 5.Operating conditions

All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		4.5	5.5	V
V _{IH}	HIGH-level input voltage		2.0	-	V
V _{IL}	LOW-level input voltage		-	0.8	V
T _{amb}	ambient temperature	operating in free-air	-40	+85	°C

9. Static characteristics

Table 6. Static characteristics

$T_{amb} = -40$	°C to +85 °C.
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{IK}	input clamping voltage	$V_{CC} = 4.5 \text{ V}; \text{ I}_{\text{I}} = -18 \text{ mA}$	-	-	-1.2	V
V _{pass}	pass voltage	$V_{I} = V_{CC} = 5.0 \ V; \ I_{O} = -100 \ \mu A$	<u>1</u> 3.6	3.9	4.2	V
l _l	input leakage current	V_{CC} = 5.5 V; V_I = GND or 5.5 V	-	-	±1	μA
I _{CC}	supply current	V_{CC} = 5.5 V; I_O = 0 mA; V_I = V_{CC} or GND	-	-	3	μA
ΔI_{CC}	additional supply current	per input; V_{CC} = 5.5 V; one input at 3.4 V, other inputs at V_{CC} or GND	<u>[3]</u> _	-	2.5	mA
CI	input capacitance	control pins; $V_I = 3 V \text{ or } 0 V$	<u>[1]</u> _	3.5	-	pF
C _{io(off)}	off-state input/output capacitance	A port; $V_O = 3 V \text{ or } 0 V$; $\overline{OE} = V_{CC}$	<u>[1]</u> _	17.5	-	pF
		B port; $V_O = 3 V \text{ or } 0 V$; $\overline{OE} = V_{CC}$	<u>[1]</u> _	4.0	-	pF
R _{ON}	ON resistance	$V_{CC} = 4 V$	<u>[4]</u>			
		V _I = 2.4 V; I _I = 15 mA	[2] _	5	20	Ω
		$V_{CC} = 4.5 V$	<u>[4]</u>			
		$V_{I} = 0 V; I_{I} = 64 mA$	<u>[1]</u> _	5	7	Ω
		$V_{I} = 0 V; I_{I} = 30 mA$	<u>[1]</u> _	5	7	Ω
		V _I = 2.4 V; I _I = 15 mA	<u>[1]</u> _	10	15	Ω

[1] Typical value is measured at V_{CC} = 5 V; T_{amb} = 25 °C.

[2] Typical value is measured at V_{CC} = 4 V; T_{amb} = 25 °C.

[3] This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

[4] Measured by the voltage drop between the A and the Bn terminals at the indicated current through the switch. The lowest voltage of the two (A or Bn) terminals determines the ON resistance.

10. Dynamic characteristics

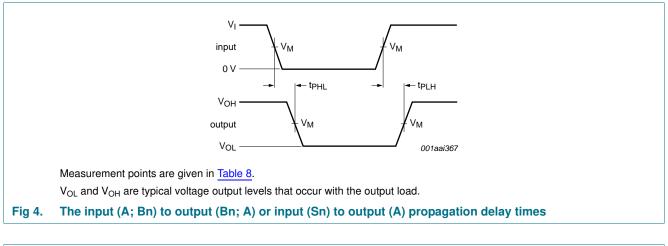
Table 7. Dynamic characteristics

 $T_{amb} = -40$ °C to +85 °C; $V_{CC} = 4.5$ V to 5.5 V; for test circuit, see <u>Figure 6</u>.

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Symbol	Parameter	Conditions	Min	Мах	Unit
t _{pd}	propagation delay	A to Bn or Bn to A; see Figure 4	[1][2] _	0.25	ns
		Sn to A; see Figure 4	^{[1][2]} 1.5	5.5	ns
t _{en}	enable time	OE to A or Bn; see Figure 5	^[2] 1.5	5.6	ns
		Sn to Bn; see Figure 5	^[2] 1.6	5.8	ns
t _{dis}	disable time	OE to A or Bn; see Figure 5	^[2] 1.9	6.4	ns
		Sn to Bn; see Figure 5	2.3	6.2	ns

[1] This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical ON resistance of the switch and a load capacitance, when driven by an ideal voltage source (zero output impedance).

11. AC waveforms



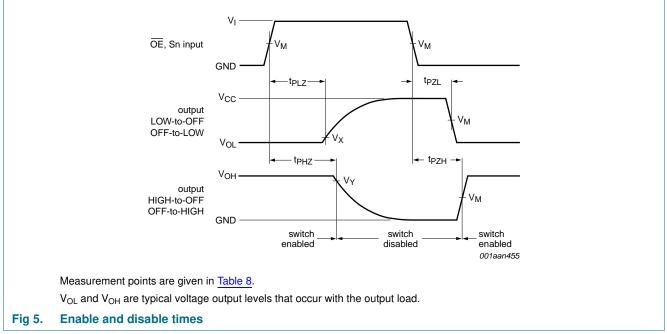


Table 8.Measurement points

Supply voltage Input		Output			
V _{CC}	VI	V _M	V _M	V _X	V _Y
4.5 V to 5.5 V	GND to 3.0 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} – 0.3 V

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12. Test information

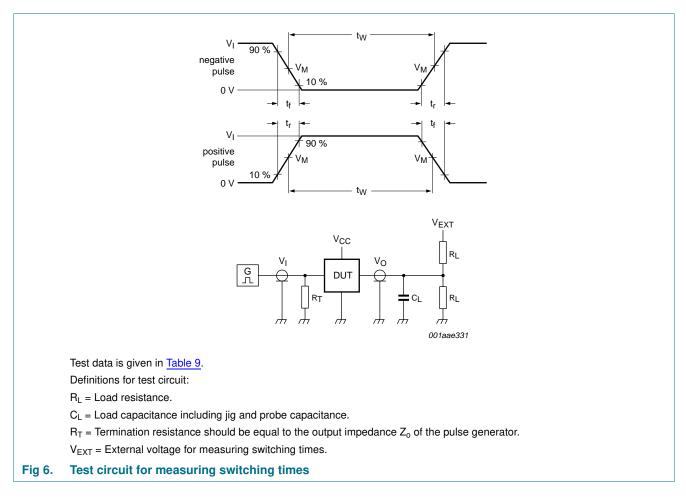


Table 9. Test data

Supply voltage	Input		Load		V _{EXT}		
V _{CC}	VI	t _r , t _f	CL	RL	t _{PLH} , t _{PHL}	t _{PLZ} , t _{PZL}	t _{PHZ} , t _{PZH}
4.5 V to 5.5 V	GND to 3.0 V	\leq 2.5 ns	50 pF	500 Ω	open	7.0 V	open

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13. Package outline

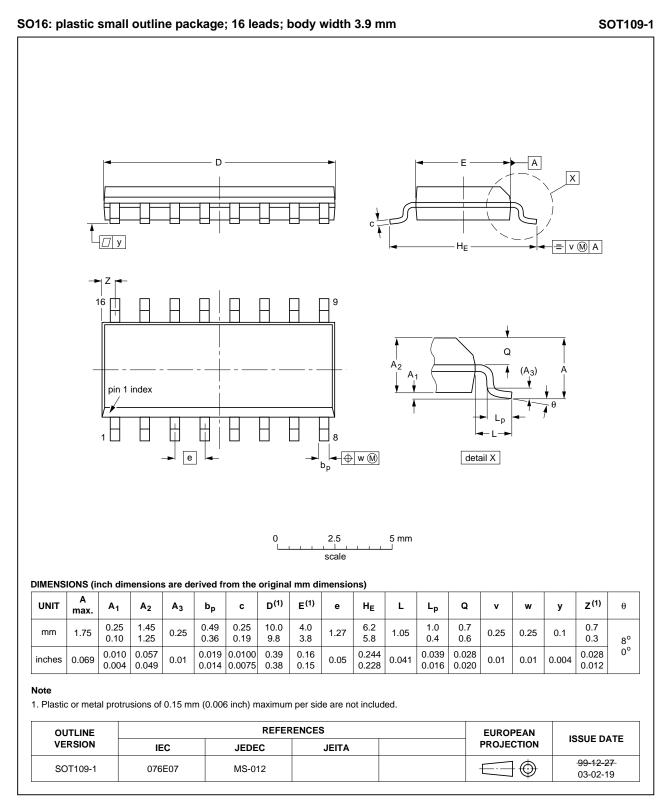


Fig 7. Package outline SOT109-1 (SO16)

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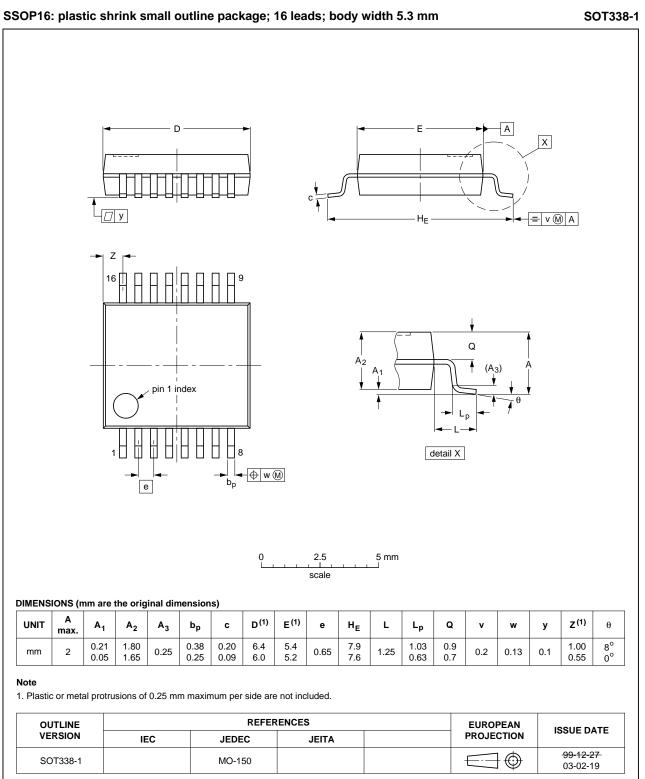
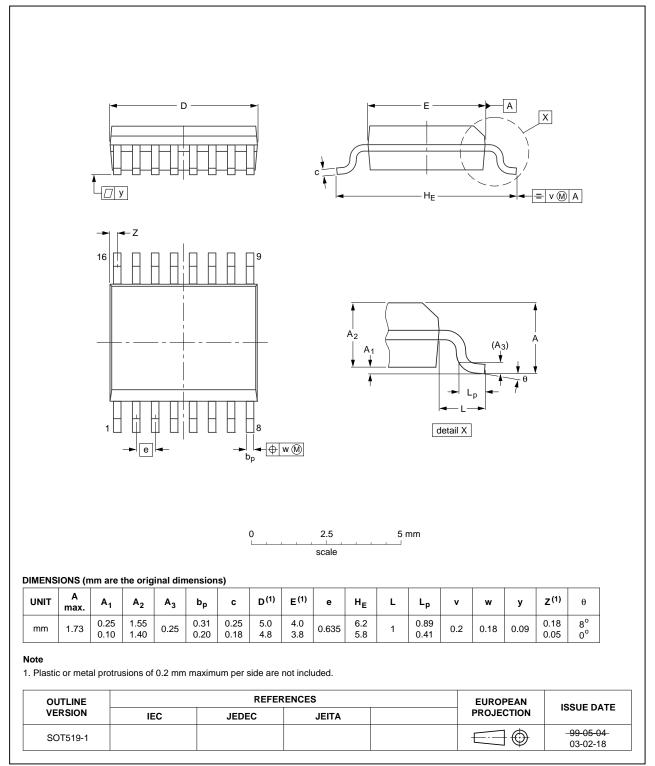


Fig 8. Package outline SOT338-1 (SSOP16)



SSOP16: plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm SOT519-1

Fig 9. Package outline SOT519-1 (SSOP16)

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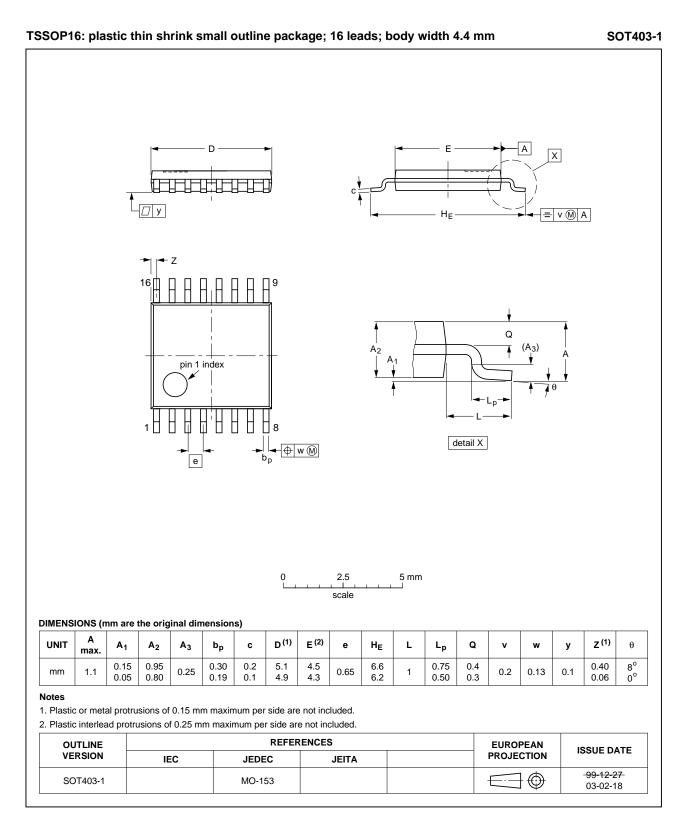


Fig 10. Package outline SOT403-1 (TSSOP16)

14. Abbreviations

Table 10. A	bbreviations
Acronym	Description
CDM	Charged Device Model
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
CBT3251 v.2	20130916	Product data sheet	-	CBT3251 v.1		
Modifications:	NXP Semice		the new identity guidelines of			
	 Legal texts have been adapted to the new company name where appropriate. 					
	 <u>Table 6</u> pass voltage modified. 					
CBT3251 v.1	20051221	Product data sheet	-	-		

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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